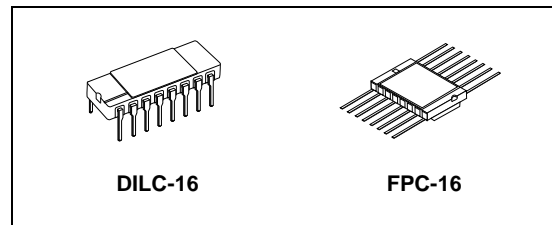


## RAD-HARD DUAL J-K FLIP FLOP WITH PRESET AND CLEAR

- HIGH SPEED :  
 $f_{MAX} = 67\text{MHz}$  (TYP.) at  $V_{CC} = 6\text{V}$
- LOW POWER DISSIPATION:  
 $I_{CC} = 2\mu\text{A}$  (MAX.) at  $T_A = 25^\circ\text{C}$
- HIGH NOISE IMMUNITY:  
 $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (MIN.)
- SYMMETRICAL OUTPUT IMPEDANCE:  
 $|I_{OH}| = I_{OL} = 4\text{mA}$  (MIN)
- BALANCED PROPAGATION DELAYS:  
 $t_{PLH} \approx t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE:  
 $V_{CC}$  (OPR) = 2V to 6V
- PIN AND FUNCTION COMPATIBLE WITH  
 54 SERIES 109
- SPACE GRADE-1: ESA SCC QUALIFIED
- 50 krad QUALIFIED, 100 krad AVAILABLE ON  
 REQUEST
- NO SEL UNDER HIGH LET HEAVY IONS  
 IRRADIATION
- DEVICE FULLY COMPLIANT WITH  
 SCC-9306-048

### DESCRIPTION

The M54HC109 is an high speed CMOS DUAL J-K FLIP FLOP WITH PRESET AND CLEAR fabricated with silicon gate C<sup>2</sup>MOS technology. In accordance with the logic level on the J and  $\bar{K}$



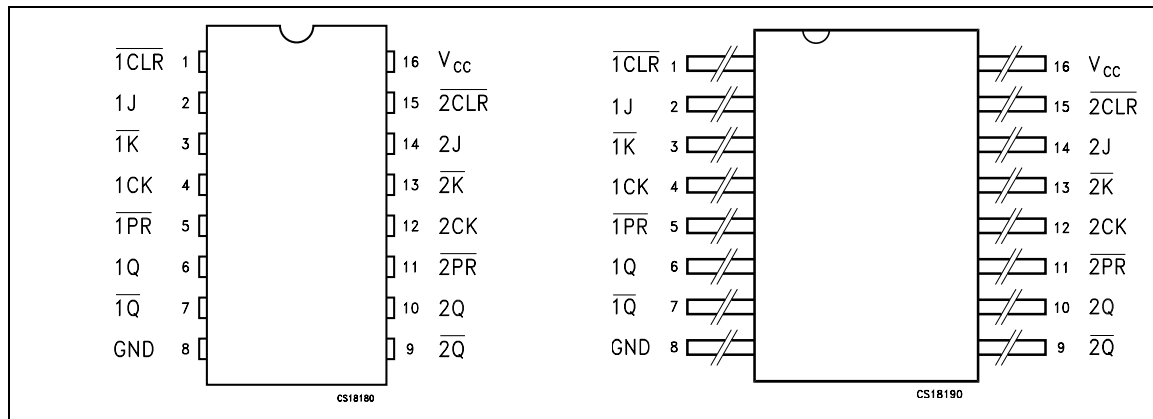
### ORDER CODES

PACKAGE	FM	EM
DILC	M54HC109D	M54HC109D1
FPC	M54HC109K	M54HC109K1

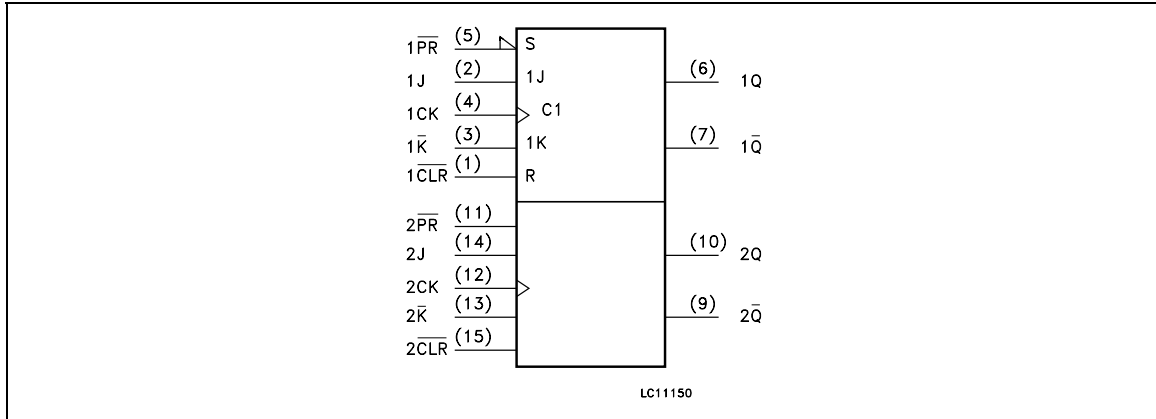
input this device changes state on positive going transition of the clock pulse. CLEAR and PRESET are independent of the clock and are accomplished by a logic low on the corresponding input.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

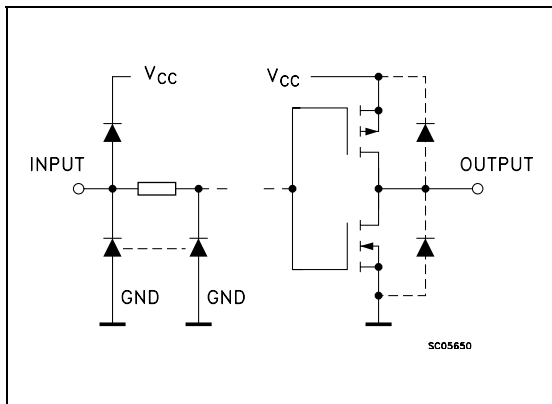
### PIN CONNECTION



IEC LOGIC SYMBOLS



INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

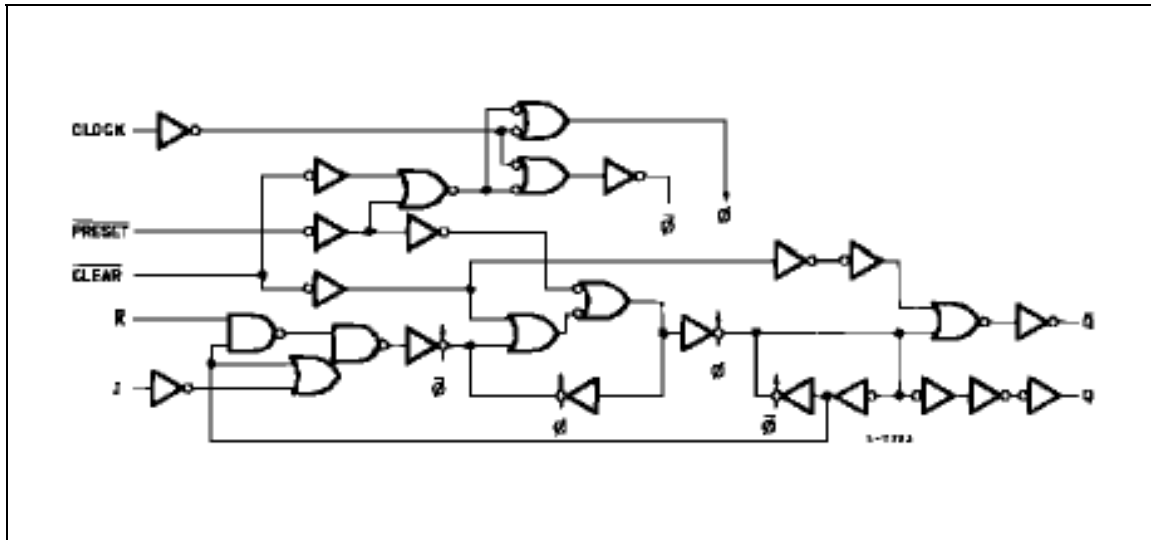
PIN N°	SYMBOL	NAME AND FUNCTION
1, 15	$\overline{1CLR}, \overline{2CLR}$	Asynchronous Reset Direct Input
2, 14, 3, 13	1J, 2J, 1K, 2K	Synchronous Inputs; Flip-Flops 1 and 2
4, 12	1CK, 2CK	Clock Input
5, 11	$\overline{1PR}, \overline{2PR}$	Asynchronous Set Direct Input (Active Low)
6, 10	1Q, 2Q	True Flip-Flop Outputs
7, 9	$\overline{1Q}, \overline{2Q}$	Complement Flip-Flop Outputs
8	GND	Ground (0V)
16	Vcc	Positive Supply Voltage

TRUTH TABLE

INPUTS					OUTPUTS		FUNCTION
$\overline{CLR}$	$\overline{PR}$	J	$\overline{K}$	CK	Q	$\overline{Q}$	
L	H	X	X	X	L	H	CLEAR
H	L	X	X	X	H	L	PRESET
L	L	X	X	X	H	H	----
H	H	L	H		Qn	$\overline{Qn}$	NO CHANGE
H	H	L	L		L	H	----
H	H	H	H		H	L	----
H	H	H	L		$\overline{Qn}$	Qn	TOGGLE
H	H	X	X		Qn	$\overline{Qn}$	NO CHANGE

X : Don't Care

## LOGIC DIAGRAM



This logic diagram has not be used to estimate propagation delays

## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	-0.5 to +7	V
$V_I$	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
$V_O$	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
$I_{IK}$	DC Input Diode Current	$\pm 20$	mA
$I_{OK}$	DC Output Diode Current	$\pm 20$	mA
$I_O$	DC Output Current	$\pm 25$	mA
$I_{CC}$ or $I_{GND}$	DC $V_{CC}$ or Ground Current	$\pm 50$	mA
$P_D$	Power Dissipation	300	mW
$T_{stg}$	Storage Temperature	-65 to +150	$^{\circ}C$
$T_L$	Lead Temperature (10 sec)	265	$^{\circ}C$

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit	
$V_{CC}$	Supply Voltage	2 to 6	V	
$V_I$	Input Voltage	0 to $V_{CC}$	V	
$V_O$	Output Voltage	0 to $V_{CC}$	V	
$T_{op}$	Operating Temperature	-55 to 125	$^{\circ}C$	
$t_r, t_f$	Input Rise and Fall Time	$V_{CC} = 2.0V$	0 to 1000	ns
		$V_{CC} = 4.5V$	0 to 500	ns
		$V_{CC} = 6.0V$	0 to 400	ns

## DC SPECIFICATIONS

Symbol	Parameter	Test Condition		Value						Unit	
		V <sub>CC</sub> (V)		T <sub>A</sub> = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
V <sub>IH</sub>	High Level Input Voltage	2.0		1.5			1.5		1.5		V
		4.5		3.15			3.15		3.15		
		6.0		4.2			4.2		4.2		
V <sub>IL</sub>	Low Level Input Voltage	2.0				0.5		0.5		0.5	V
		4.5				1.35		1.35		1.35	
		6.0				1.8		1.8		1.8	
V <sub>OH</sub>	High Level Output Voltage	2.0	I <sub>O</sub> =-20 μA	1.9	2.0		1.9		1.9		V
		4.5	I <sub>O</sub> =-20 μA	4.4	4.5		4.4		4.4		
		6.0	I <sub>O</sub> =-20 μA	5.9	6.0		5.9		5.9		
		4.5	I <sub>O</sub> =-4.0 mA	4.18	4.31		4.13		4.10		
		6.0	I <sub>O</sub> =-5.2 mA	5.68	5.8		5.63		5.60		
V <sub>OL</sub>	Low Level Output Voltage	2.0	I <sub>O</sub> =20 μA		0.0	0.1		0.1		0.1	V
		4.5	I <sub>O</sub> =20 μA		0.0	0.1		0.1		0.1	
		6.0	I <sub>O</sub> =20 μA		0.0	0.1		0.1		0.1	
		4.5	I <sub>O</sub> =4.0 mA		0.17	0.26		0.33		0.40	
		6.0	I <sub>O</sub> =5.2 mA		0.18	0.26		0.33		0.40	
I <sub>I</sub>	Input Leakage Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND			± 0.1		± 1		± 1	μA
I <sub>CC</sub>	Quiescent Supply Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND			2		20		40	μA

AC ELECTRICAL CHARACTERISTICS ( $C_L = 50$  pF, Input  $t_r = t_f = 6$  ns)

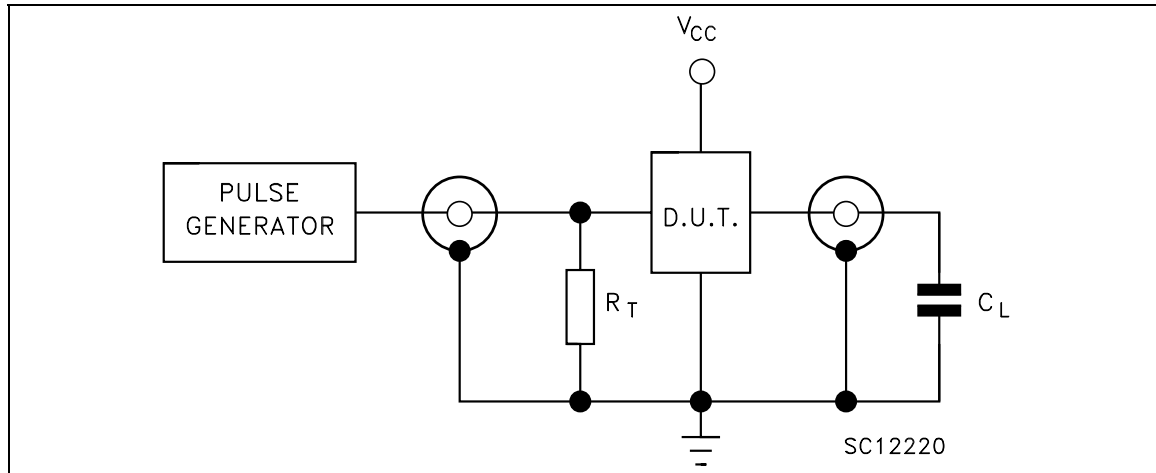
Symbol	Parameter	Test Condition		Value						Unit	
		$V_{CC}$ (V)		$T_A = 25^\circ\text{C}$			$-40$ to $85^\circ\text{C}$		$-55$ to $125^\circ\text{C}$		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
$t_{TLH}$ $t_{THL}$	Output Transition Time	2.0			30	75		95		110	ns
		4.5			8	15		19		22	
		6.0			7	13		16		19	
$t_{PLH}$ $t_{PHL}$	Propagation Delay Time (CK - Q, Q)	2.0			50	150		190		225	ns
		4.5			16	30		38		45	
		6.0			13	26		32		38	
$t_{PLH}$ $t_{PHL}$	Propagation Delay Time (CLR, PR - Q, Q)	2.0			50	150		190		225	ns
		4.5			16	30		38		45	
		6.0			13	26		32		38	
$f_{MAX}$	Maximum Clock Frequency	2.0			6.2	17		5		4.2	MHz
		4.5			31	59		25		21	
		6.0			37	67		30		25	
$t_{W(H)}$ $t_{W(L)}$	Minimum Pulse Width (CK)	2.0			15	75		95		110	ns
		4.5			6	15		19		22	
		6.0			6	13		16		19	
$t_{W(L)}$	Minimum Pulse Width (CLR, PR)	2.0			15	75		95		110	ns
		4.5			6	15		19		22	
		6.0			6	13		16		19	
$t_s$	Minimum Set-Up Time	2.0			17	75		95		110	ns
		4.5			5	15		19		22	
		6.0			4	13		16		19	
$t_h$	Minimum Hold Time	2.0				0		0		0	ns
		4.5				0		0		0	
		6.0					0		0	0	
$t_{REM}$	Minimum Removal Time (CLR, PR)	2.0			13	50		65		75	ns
		4.5			4	10		13		15	
		6.0			3	9		11		13	

## CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition		Value						Unit	
		$V_{CC}$ (V)		$T_A = 25^\circ\text{C}$			$-40$ to $85^\circ\text{C}$		$-55$ to $125^\circ\text{C}$		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
$C_{IN}$	Input Capacitance	5.0			5	10		10		10	pF
$C_{PD}$	Power Dissipation Capacitance (note 1)	5.0			41						pF

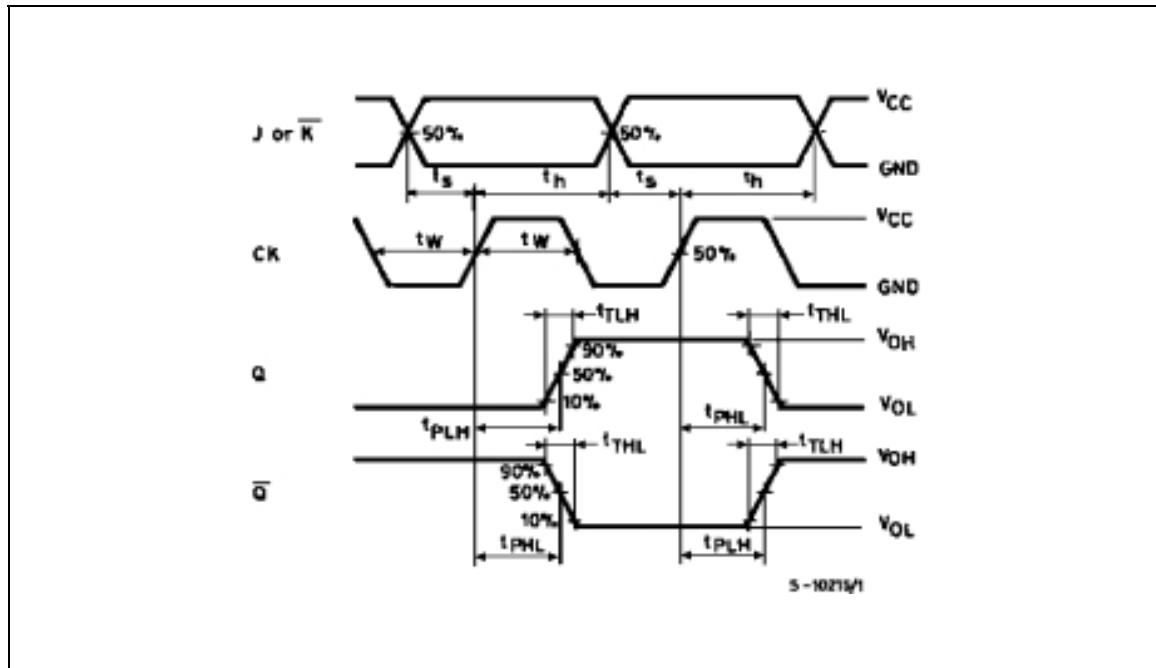
1)  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation.  $I_{CC(oper)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/2$  (per FLIP/FLOP)

TEST CIRCUIT

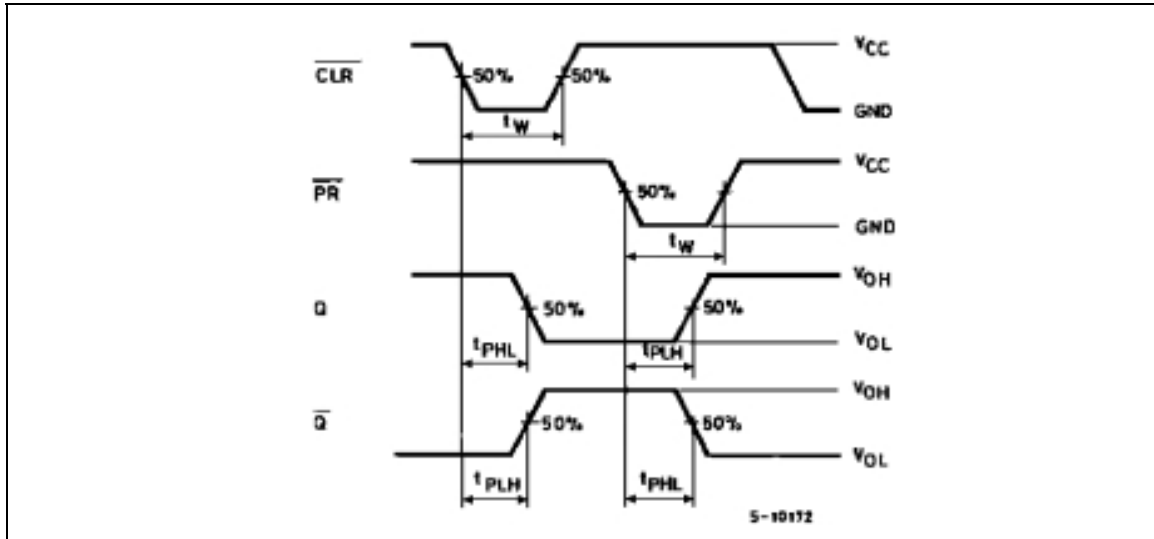


$C_L = 50\text{pF}$  or equivalent (includes jig and probe capacitance)  
 $R_T = Z_{OUT}$  of pulse generator (typically  $50\Omega$ )

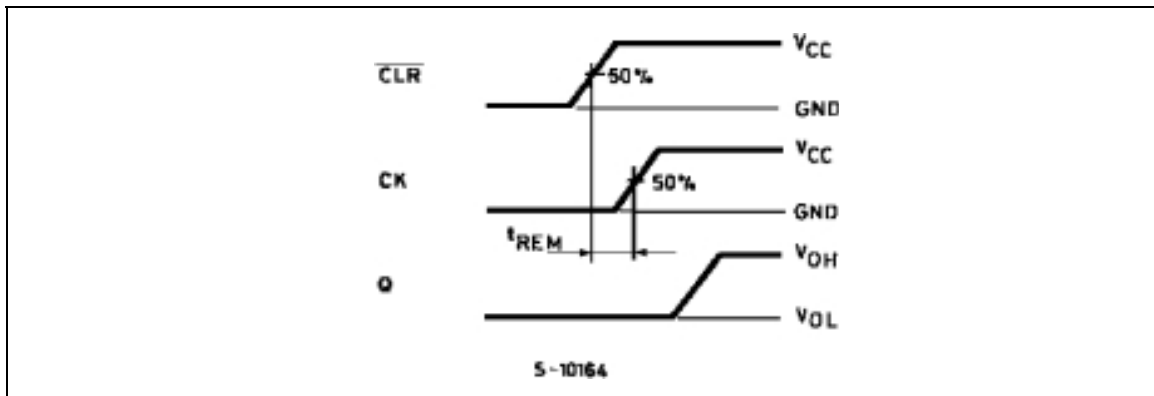
WAVEFORM 1: PROPAGATION DELAY TIMES, SETUP AND HOLD TIMES, MINIMUM PULSE WIDTH (CK) ( $f=1\text{MHz}$ ; 50% duty cycle)



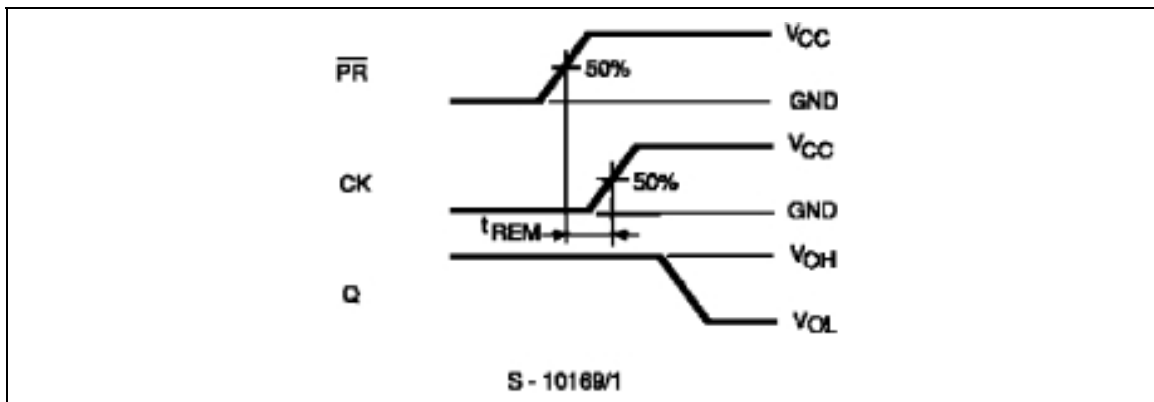
**WAVEFORM 2 : PROPAGATION DELAY TIMES , MINIMUM PULSE WIDTH ( $\overline{\text{CLR}}$ ), ( $\overline{\text{PR}}$ )**  
 (f=1MHz; 50% duty cycle)



**WAVEFORM 3 : MINIMUM REMOVAL TIME ( $\overline{\text{CLR}}$  to CK)** (f=1MHz; 50% duty cycle)

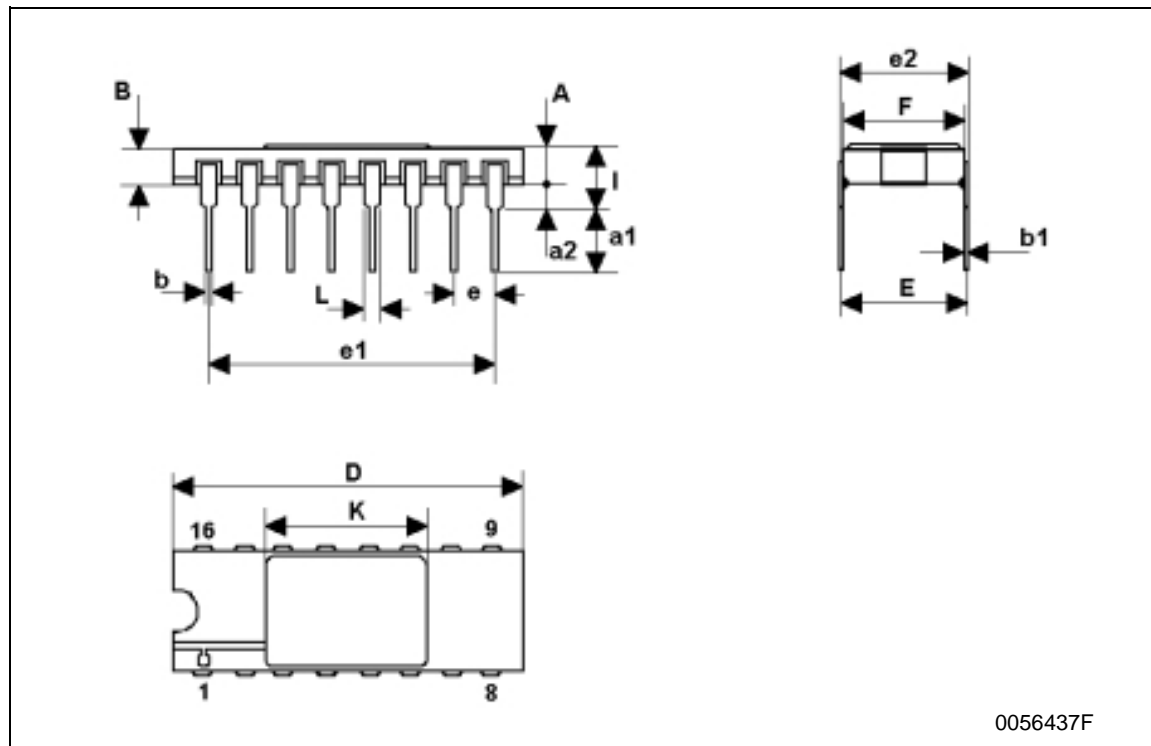


**WAVEFORM 4 : MINIMUM REMOVAL TIME ( $\overline{\text{PR}}$  to CK)** (f=1MHz; 50% duty cycle)



## DILC-16 MECHANICAL DATA

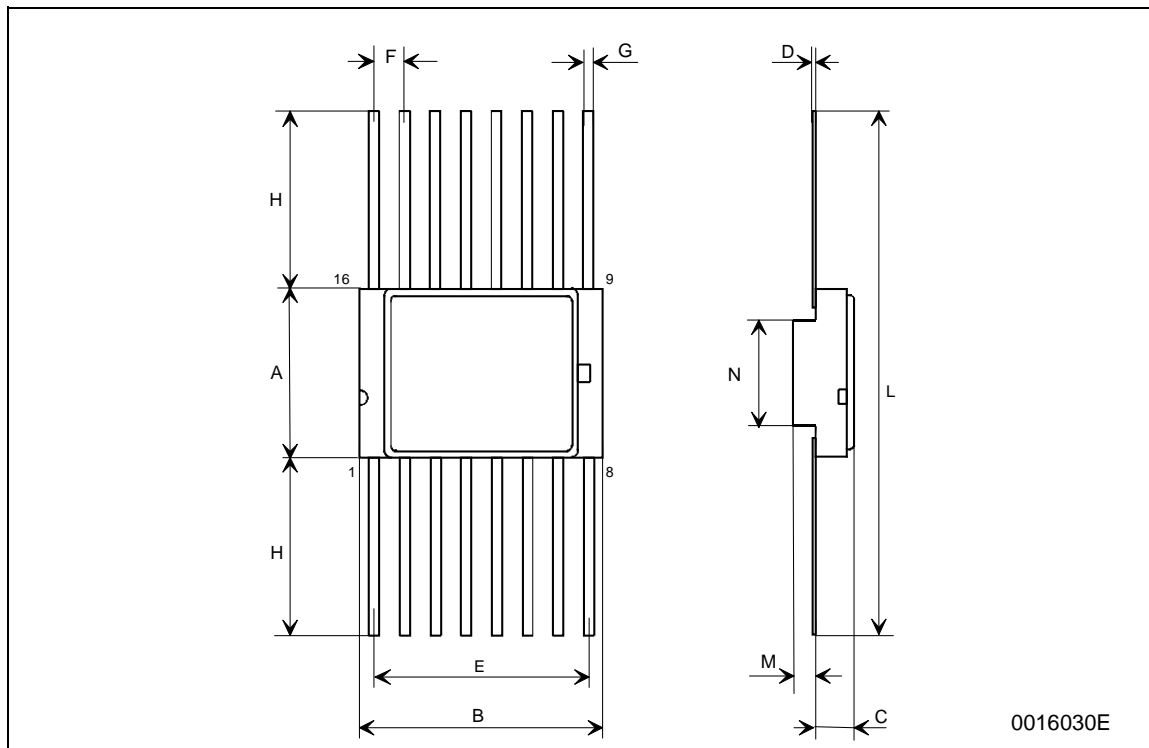
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	2.1		2.71	0.083		0.107
a1	3.00		3.70	0.118		0.146
a2	0.63	0.88	1.14	0.025	0.035	0.045
B	1.82		2.39	0.072		0.094
b	0.40	0.45	0.50	0.016	0.018	0.020
b1	0.20	0.254	0.30	0.008	0.010	0.012
D	20.06	20.32	20.58	0.790	0.800	0.810
e	7.36	7.62	7.87	0.290	0.300	0.310
e1		2.54			0.100	
e2	17.65	17.78	17.90	0.695	0.700	0.705
e3	7.62	7.87	8.12	0.300	0.310	0.320
F	7.29	7.49	7.70	0.287	0.295	0.303
I			3.83			0.151
K	10.90		12.1	0.429		0.476
L	1.14		1.5	0.045		0.059





<b>FPC-16 MECHANICAL DATA</b>
-------------------------------

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	6.75	6.91	7.06	0.266	0.272	0.278
B	9.76	9.94	10.14	0.384	0.392	0.399
C	1.49		1.95	0.059		0.077
D	0.102	0.127	0.152	0.004	0.005	0.006
E	8.76	8.89	9.01	0.345	0.350	0.355
F		1.27			0.050	
G	0.38	0.43	0.48	0.015	0.017	0.019
H	6.0			0.237		
L	18.75		22.0	0.738		0.867
M	0.33	0.38	0.43	0.013	0.015	0.017
N		4.31			0.170	



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics  
All other names are the property of their respective owners

© 2004 STMicroelectronics - All Rights Reserved  
STMicroelectronics GROUP OF COMPANIES

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

<http://www.st.com>